



AP2210
300mA RF ULDO REGULATOR

Description

The AP2210 is a 300mA ULDO regulator which provides very low noise, ultra-low dropout voltage (typically 250mV at 300mA), very low standby current (1µA maximum), and excellent power supply ripple rejection (PSRR 75dB at 100Hz). This device is used in battery powered applications, such as handsets and PDAs; and in noise sensitive applications, such as RF electronics.

The AP2210 also features individual logic compatible enable/shutdown control inputs, a low power shutdown mode for extended battery life, overcurrent protection, overtemperature protection, and reversed current protection.

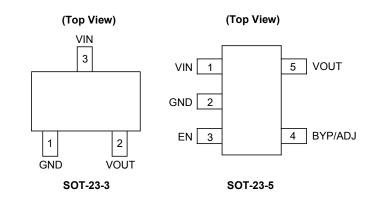
The AP2210 has 2.5V, 2.8V, 3.0V, 3.3V, 3.6V, 4.0V, 5.0V, and ADJ versions.

The AP2210 is available in the space saving SOT-23-3 and SOT-23-5 packages.

Features

- Up to 300mA Output Current
- Excellent ESR Stability
- Low Standby Current
- Low Dropout Voltage: V_{DROP} = 250mV at 300mA
- High Output Accuracy: ±1%
- Good Ripple Rejection Ability: 75dB at 100Hz and I_{OUT} = 100μA
- Tight Load and Line Regulation
- Low Temperature Coefficient
- Over-Current Protection
- Thermal Protection
- Reverse Current Protection
- Logic-controlled Enable
- Moisture Sensitivity: Level 3 Per J-STD-020
- Terminals: SOT-23-3/SOT-23-5 Finish—Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight:
 - SOT-23-3: 0.014 grams (Approximate)
 - SOT-23-5: 0.015 grams (Approximate)
 - Totally Lead-Free; RoHS Compliant (Notes 1 & 2)
- Lead-Free Packages, Available in "Green" Molding Compound: SOT-23-3, SOT-23-5
 - Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
 - Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Pin Assignments



Applications

- Cellular Phones
- Cordless Phones
- Wireless Communicators
- PDAs/Palmtops
- PC Motherboards
- Consumer Electronics

Notes:

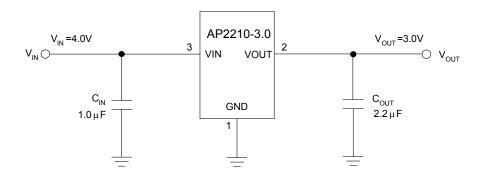
- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

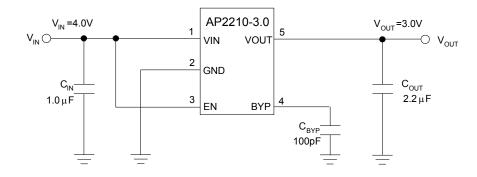
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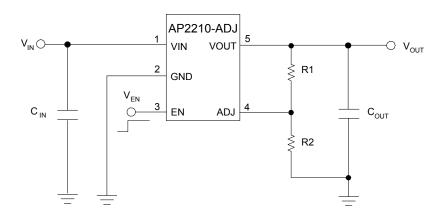


Typical Applications Circuit (Note 4)





For Fixed Version



 $V_{OUT} = 1.25V*(1+R2/R1)$

For Adjustable Version

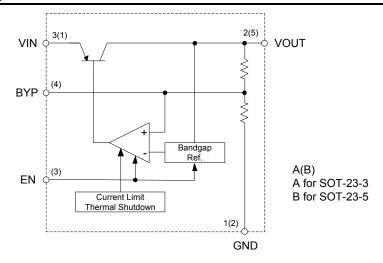
Notes:
4. Dropout voltage is 250mV when T_A = +25°C. In order to obtain a normal output voltage, V_{OUT}+0.25V is the minimum input voltage which will result a low PSRR, imposing a bad influence on system. Therefore, the recommended input voltage is V_{OUT}+1V to 13.2V. For AP2210-3.0 version, its input voltage can be set from 4V (V_{OUT}+1V) to 13.2V.



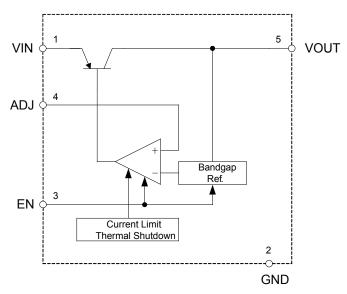
Pin Descriptions

Pin N	Number	D: N				
SOT23-3	SOT23-3 SOT23-5 Pin Name		Function			
1	2	GND	Ground			
2	5	VOUT	Regulated output voltage			
3	1	VIN	Input voltage			
_	3	EN	Enable input: CMOS or TTL compatible input. Logic high=enable, logic low=shutdown			
_	4	BYP/ADJ	Bypass capacitor for low noise operation/Adjustable Output			

Functional Block Diagram



Fixed Version



ADJ Version (For SOT-23-5)



Absolute Maximum Ratings (Note 5)

Symbol	Parameter	Rat	ting	Unit	
V _{IN}	Supply Input Voltage	1	5	V	
V _{EN}	Enable Input Voltage	1	5	V	
P _D	Power Dissipation		Internally Limited (Thermal Protection)		
T _{LEAD}	Lead Temperature (Soldering, 10sec)	+260		°C	
TJ	Junction Temperature	+1	50	°C	
T _{STG}	Storage Temperature	-65 to	+150	°C	
ESD	ESD (Machine Model)	300		V	
	The arrest Designation of Alexander	SOT-23-3 200		-011	
θ_{JA}	Thermal Resistance (No Heatsink)	SOT-23-5	200	°C/W	

Notes: 5. Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Unit
V _{IN}	Supply Input Voltage	2.5	13.2	٧
V _{EN}	Enable Input Voltage	0	13.2	٧
TJ	Operating Junction Temperature	-40	+125	°C



AP2210-2.5 Electrical Characteristics (V_{IN} = 3.5V, I_{OUT} = 100 μ A, C_{IN} = 1.0 μ F, C_{OUT} = 2.2 μ F, V_{EN} \geq 2.0V, T_J = +25°C, **Bold** typeface applies over -40°C \leq T_J \leq +125°C (Note 6), unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
-			-1	_	1	
$\Delta V_{ m OUT}/V_{ m OUT}$	Output Voltage Accuracy	Variation from specified V _{OUT}	-2	_	2	%
ΔV _{OUT} /ΔΤ	Output Voltage Temperature	_	† —	120		μV/°C
(ΔV _{ΟυΤ} /V _{ΟυΤ})/ΔΤ	Coefficient (Note 7)	_	† —	48		ppm/°C
			<u> </u>	1.5	4.5	
V _{RLINE}	Line Regulation	V _{IN} = 3.5V to 13.2V		_	12	mV
			_	1	6	
V_{RLOAD}	Load Regulation (Note 8)	I _{OUT} = 0.1mA to 300mA	_	_	30	mV
			<u> </u>	15	50	
		Ι _Ο ΕΕΕΕΕΕΕΕΕΕΕΕΕΕΕΕΕΕΕΕΕΕΕΕΕΕΕΕΕΕΕΕΕΕΕΕ	_	_	70	
	Dropout Voltage (Note 9)		_	110	150	
		I _{OUT} = 50mA	_	_	230	mV
V _{DROP} Dropout Voltage (Note 9)		I _{OUT} = 100mA	_	140	250	
				_	300	
	4504	_	165	275		
		I _{OUT} = 150mA	_	_	350	
		J. 000 A	_	250	400	
		I _{OUT} = 300mA	_	_	500	
	Others allow Occurrent	V _{EN} ≤ 0.4V (shutdown)	_	0.01	1	
I _{STD}	Standby Current	V _{EN} ≤ 0.18V (shutdown)	_	_	5	μΑ
		V > 2.0V - 400vA	_	100	150	
		V _{EN} ≥ 2.0V, I _{OUT} = 100μA	_		180]
		V _{EN} ≥ 2.0V, I _{OUT} = 50mA		350	600	μA
laun.	Cround Bin Current (Note 10)	VEN ≥ 2.0 V, IOUT - 30IIIA	_	_	800	
I _{GND}	Ground Pin Current (Note 10)	V _{EN} ≥ 2.0V, I _{OUT} = 150mA	_	1.3	1.9	
		VEN < 2.0V, IOUT = IDUIIA	<u> </u>	_	2.5]
	V _{EN} ≥ 2.0V, I _{OUT} = 300mA	_	4	10	mA	
		v _{EN} = 2.0 v, I _{OUT} - 300IIIA	_	_	15	
PSRR	Ripple Rejection	f = 100Hz, I _{OUT} = 100μA	_	75		dB
I _{LIMIT}	Current Limit	V _{OUT} = 0V	_	450	900	mA



AP2210-2.5 Electrical Characteristics (Cont.) (V_{IN} = 3.5V, I_{OUT} = 100μA, C_{IN} = 1.0μF, C_{OUT} = 2.2μF, V_{EN} ≥ 2.0V, T_J = +25°C, **Bold** typeface applies over $-40^{\circ}\text{C} \le T_{\text{J}} \le +125^{\circ}\text{C}$ (Note 6), unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
e _{no}	Output Noise	I_{OUT} = 50mA, C_{OUT} = 2.2 μ F, 100 μ F from BYP to GND	_	260	_	nV/\sqrt{Hz}
.,	Enable Input Logic-low Voltage				0.4	.,
V_{IL}		Regulator shutdown	_	_	0.18	V
V_{IH}	Enable Input Logic-high Voltage	Regulator enabled	2.0	_	_	٧
		V _{IL} ≤ 0.4V	_	0.01	1	
IIL	I _{IL} Enable Input Logic-low Current	V _{IL} ≤ 0.18V	_	_	2	μA
		V _{IL} ≥ 2.0V	_	5	20	
IIH	Enable Input Logic-high Current	V _{IL} ≥ 2.0V		_	25	μΑ

- 6. Specifications in bold type are limited to -40°C ≤ T_J ≤ +125°C. Limits over temperature are guaranteed by design, but not tested in production.
- Specifications in bold type are limited to -40°C ≤ 1 3 ≤ +125°C. Limits over temperature are guaranteed by design, but not tested in production.
 Output voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.
 Regulation is measured at constant junction temperature using low duty cycle pulse testing. Parts are tested for load regulation in the load range from 0.1mA to 300mA. Changes in output voltage due to heating effects are covered by the thermal regulation specification.
 Dropout voltage is defined as the input to output differential at which the output voltage drops 1% (T_J = +25°C) or 2% (-40°C ≤ T_J ≤ +125°C) below its nominal value measured at 1V differential.
- 10. Ground pin current is the regulator quiescent current plus pass transistor base current. The total current drawn from the supply is the sum of the load current plus the ground pin current.



AP2210-2.8 Electrical Characteristics (V_{IN} = 3.8V, I_{OUT} = 100 μ A, C_{IN} = 1.0 μ F, C_{OUT} = 2.2 μ F, V_{EN} \geq 2.0V, T_J = +25°C, **Bold** typeface applies over -40°C \leq T_J \leq +125°C (Note 6), unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
		V : 6 (-1	_	1	0/
$\Delta V_{OUT}/V_{OUT}$	Output Voltage Accuracy	Variation from specified V _{OUT}	-2	_	2	%
ΔV _{OUT} /ΔΤ	Output Voltage Temperature	_		120	_	μV/°C
(ΔV _{ΟυΤ} /V _{ΟυΤ})/ΔΤ	Coefficient (Note 7)	_		42.8		ppm/°C
V	Line Degulation	V _{IN} = 3.8V to 13.2V		1.5	4.5	m\/
V _{RLINE}	Line Regulation	VIN = 3.8V to 13.2V			12	mV
V	Load Degulation (Nate 0)	- 0.4mA to 200mA		1	6	\/
V_{RLOAD}	Load Regulation (Note 8)	I _{OUT} = 0.1mA to 300mA			30	mV
	V _{DROP} Dropout Voltage (Note 9)	- 100vA		15	50	
		Ι _Ο υτ = 100μΑ		_	70	
		I _{OUT} = 50mA		110	150	
V					230	mV
		I _{OUT} = 100mA		140	250	
VDROP				_	300	
		I _{OUT} = 150mA		165	275	
					350	
				250	400	
		I _{OUT} = 300mA		_	500	
	0, 1, 0	V _{EN} ≤ 0.4V (shutdown)		0.01	1	
I _{STD}	Standby Current	V _{EN} ≤ 0.18V (shutdown)	_	_	5	μA
		V > 0.0V 400vA	_	100	150	
		V _{EN} ≥ 2.0V, I _{OUT} = 100μA			180	
		\\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \		350	600	μΑ
	One and Bir Output (Nata 40)	V _{EN} ≥ 2.0V, I _{OUT} = 50mA		_	800	
IGND	I _{GND} Ground Pin Current (Note 10)	V > 2.0V 450A		1.3	1.9	
	V _{EN} ≥ 2.0V, I _{OUT} = 150mA	_	_	2.5	mA	
	V > 2.0V = 200m4		4	10		
		V _{EN} ≥ 2.0V, I _{OUT} = 300mA		_	15	
PSRR	Ripple Rejection	f = 100Hz, I _{OUT} = 100μA		75		dB
I _{LIMIT}	Current Limit	V _{OUT} = 0V	_	450	900	mA



AP2210-2.8 Electrical Characteristics (Cont.) (V_{IN} = 3.8V, I_{OUT} = 100μA, C_{IN} = 1.0μF, C_{OUT} = 2.2μF, V_{EN} ≥ 2.0V, T_J = +25°C, **Bold** typeface applies over $-40^{\circ}\text{C} \le T_{\text{J}} \le +125^{\circ}\text{C}$ (Note 6), unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
e _{no}	Output Noise	I _{OUT} = 50mA, C _{OUT} = 2.2μF, 100pF from BYP to GND	_	260	_	nV/\sqrt{Hz}
.,					0.4	
V_{IL}	Enable Input Logic-low Voltage	Regulator shutdown	_	_	0.18	V
V _{IH}	Enable Input Logic-high Voltage	Regulator enabled	2.0	_		V
		V _{IL} ≤ 0.4V	_	0.01	1	
I _{IL}	Enable Input Logic-low Current	V _{IL} ≤ 0.18V	_	_	2	μA
		V _{IL} ≥ 2.0V	_	5	20	
I _{IH}	Enable Input Logic-high Current	V _{IL} ≥ 2.0V	_	_	25	μA

- 6. Specifications in bold type are limited to -40°C ≤ T_J ≤ +125°C. Limits over temperature are guaranteed by design, but not tested in production.
- Specifications in bold type are limited to -40°C ≤ 1 3 ≤ +125°C. Limits over temperature are guaranteed by design, but not tested in production.
 Output voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.
 Regulation is measured at constant junction temperature using low duty cycle pulse testing. Parts are tested for load regulation in the load range from 0.1mA to 300mA. Changes in output voltage due to heating effects are covered by the thermal regulation specification.
 Dropout voltage is defined as the input to output differential at which the output voltage drops 1% (T_J = +25°C) or 2% (-40°C ≤ T_J ≤ +125°C) below its nominal value measured at 1V differential.
- 10. Ground pin current is the regulator quiescent current plus pass transistor base current. The total current drawn from the supply is the sum of the load current plus the ground pin current.



AP2210-3.0 Electrical Characteristics ($V_{IN} = 4V$, $I_{OUT} = 100\mu A$, $C_{IN} = 1.0\mu F$, $C_{OUT} = 2.2\mu F$, $V_{EN} \ge 2.0V$, $T_J = +25^{\circ}C$, **Bold** typeface applies over -40°C $\le T_J \le +125^{\circ}C$ (Note 6), unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
			-1	_	1	0,
$\Delta V_{OUT}/V_{OUT}$	Output Voltage Accuracy	Variation from specified V _{OUT}	-2	_	2	%
ΔV _{OUT} /ΔΤ	Output Voltage Temperature	_	_	120	_	μV/°C
(ΔV _{OUT} /V _{OUT})/ΔT	Coefficient (Note 7)	_	_	40	_	ppm/°C
			_	1.5	4.5	
V _{RLINE}	Line Regulation	V _{IN} = 4V to 13.2V	_	_	12	mV
			_	1	6	
V_{RLOAD}	Load Regulation (Note 8)	I _{OUT} = 0.1mA to 300mA	_	_	30	mV
			_	15	50	
		I _{OUT} = 100μA	_	_	70	
V _{DROP} Dropout Voltage (Note 9)	Dropout Voltage (Note 9)		_	110	150	
		I _{OUT} = 50mA	_	_	230	mV
		I _{OUT} = 100mA	_	140	250	
			_		300	
		_	165	275		
		I _{OUT} = 150mA	_		350	
			_	250	400	
					500	
		V _{EN} ≤ 0.4V (shutdown)	_	0.01	1	
I _{STD}	Standby Current	V _{EN} ≤ 0.18V (shutdown)	_	_	5	μΑ
			_	100	150	
		$V_{EN} \ge 2.0V$, $I_{OUT} = 100 \mu A$	_	_	180	μΑ
				350	600	
		$V_{EN} \ge 2.0V$, $I_{OUT} = 50mA$			800	-
I _{GND}	Ground Pin Current (Note 10)		1	1.3	1.9	
		V _{EN} ≥ 2.0V, I _{OUT} = 150mA	_	_	2.5	mA
			1	4	10	
		V _{EN} ≥ 2.0V, I _{OUT} = 300mA		_	15	-
PSRR	Ripple Rejection	f = 100Hz, I _{OUT} = 100μA	<u> </u>	75	_	dB
I _{LIMIT}	Current Limit	V _{OUT} = 0V	<u> </u>	450	900	mA



AP2210-3.0 Electrical Characteristics (Cont.) (V_{IN} = 4V, I_{OUT} = 100µA, C_{IN} = 1.0µF, C_{OUT} = 2.2µF, V_{EN} ≥ 2.0V, T_J = +25°C, **Bold** typeface applies over -40°C \leq T_J \leq +125°C (Note 6), unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
e _{no}	Output Noise	I_{OUT} = 50mA, C_{OUT} = 2.2 μ F, 100pF from BYP to GND		260	_	nV/\sqrt{Hz}
.,					0.4	.,
V _{IL}	Enable Input Logic-low Voltage	Regulator shutdown	_	_	0.18	V
V _{IH}	Enable Input Logic-high Voltage	Regulator enabled	2.0	_	_	٧
		V _{IL} ≤ 0.4V	_	0.01	1	
I _{IL}	Enable Input Logic-low Current	V _{IL} ≤ 0.18V	_		2	μΑ
		V _{IL} ≥ 2.0V	_	5	20	
Іін	Enable Input Logic-high Current	V _{IL} ≥ 2.0V	_	_	25	μΑ

- 6. Specifications in bold type are limited to -40°C ≤ T_J ≤ +125°C. Limits over temperature are guaranteed by design, but not tested in production.
- 7. Output voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.
- Output voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.
 Regulation is measured at constant junction temperature using low duty cycle pulse testing. Parts are tested for load regulation in the load range from 0.1mA to 300mA. Changes in output voltage due to heating effects are covered by the thermal regulation specification.
 Dropout voltage is defined as the input to output differential at which the output voltage drops 1% (T_J = +25°C) or 2% (-40°C ≤ T_J ≤ +125°C) below its nominal value measured at 1V differential.
- 10. Ground pin current is the regulator quiescent current plus pass transistor base current. The total current drawn from the supply is the sum of the load current plus the ground pin current.



AP2210-3.3 Electrical Characteristics (V_{IN} = 4.3V, I_{OUT} = 100 μ A, C_{IN} = 1.0 μ F, C_{OUT} = 2.2 μ F, V_{EN} \geq 2.0V, T_J = +25°C, **Bold** typeface applies over -40°C \leq T_J \leq +125°C (Note 6), unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
			-1		1	
$\Delta V_{ m OUT}/V_{ m OUT}$	Output Voltage Accuracy	Variation from specified V _{OUT}	-2		2	%
ΔV _{OUT} /ΔΤ	Output Voltage Temperature	_	_	120	_	μV/°C
(ΔV _{ΟυΤ} /V _{ΟυΤ})/ΔΤ	Coefficient (Note 7)	_	_	36.3	_	ppm/°C
.,		1 2 4 2 4 4 2 4 4 2 4 4 4 4 4 4 4 4 4 4	_	1.5	4.5	.,,
V _{RLINE}	Line Regulation	V _{IN} = 4.3V to 13.2V	_	_	12	mV
V	15 16 (11 0)	0.4	_	1	6	.,
V_{RLOAD}	Load Regulation (Note 8)	I _{OUT} = 0.1mA to 300mA	_	_	30	mV
			_	15	50	
		Ι _{ΟUT} = 100μΑ	_	_	70	
			_	110	150	
V _{DROP} Dropout Voltage (Note 9)	Dropout Voltage (Note 9)	I _{OUT} = 50mA	_	_	230	mV
		I _{OUT} = 100mA	_	140	250	
			_		300	
		_	165	275		
	I _{OUT} = 150mA	I _{OUT} = 150mA	_	_	350	
		L = 200mA	_	250	400	
		I _{OUT} = 300mA	_	_	500	
		V _{EN} ≤ 0.4V (shutdown)	_	0.01	1	
I _{STD}	Standby Current	V _{EN} ≤ 0.18V (shutdown)	_	_	5	μA
			_	100	150	
		V _{EN} ≥ 2.0V, I _{OUT} = 100μA	_	_	180	
			_	350	600	μA
	0 15: 0 16: 15:	V _{EN} ≥ 2.0V, I _{OUT} = 50mA	_	_	800	
I_{GND}	Ground Pin Current (Note 10)	V	_	1.3	1.9	
	V _{EN} ≥ 2.0V, I _{OUT} = 150mA	_	_	2.5	- 	
		V	_	4	10	mA -
		V _{EN} ≥ 2.0V, I _{OUT} = 300mA	_	_	15	
PSRR	Ripple Rejection	f = 100Hz, I _{OUT} = 100μA	_	75	_	dB
I _{LIMIT}	Current Limit	V _{OUT} = 0V	_	450	900	mA



AP2210-3.3 Electrical Characteristics (Cont.) (V_{IN} = 4.3V, I_{OUT} = 100μA, C_{IN} = 1.0μF, C_{OUT} = 2.2μF, V_{EN} ≥ 2.0V, T_J = +25°C, **Bold** typeface applies over $-40^{\circ}\text{C} \le T_{\text{J}} \le +125^{\circ}\text{C}$ (Note 6), unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
e _{no}	Output Noise	I_{OUT} = 50mA, C_{OUT} = 2.2 μ F, 100pF from BYP to GND		260	_	nV/\sqrt{Hz}
V	Enable Input Logic-low Voltage		_	_	0.4	.,
V_{IL}		Regulator shutdown	_	_	0.18	V
V _{IH}	Enable Input Logic-high Voltage	Regulator enabled	2.0	_	_	V
		V _{IL} ≤ 0.4V		0.01	1	
I _Ι L	I _{IL} Enable Input Logic-low Current	V _{IL} ≤ 0.18V	_		2	μΑ
I _{IН}		V _{IL} ≥ 2.0V	_	5	20	μА
	Enable Input Logic-high Current	V _{IL} ≥ 2.0V			25	

- 6. Specifications in bold type are limited to -40°C ≤ T_J ≤ +125°C. Limits over temperature are guaranteed by design, but not tested in production.
- Specifications in bold type are limited to -40°C ≤ 1 3 ≤ +125°C. Limits over temperature are guaranteed by design, but not tested in production.
 Output voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.
 Regulation is measured at constant junction temperature using low duty cycle pulse testing. Parts are tested for load regulation in the load range from 0.1mA to 300mA. Changes in output voltage due to heating effects are covered by the thermal regulation specification.
 Dropout voltage is defined as the input to output differential at which the output voltage drops 1% (T_J = +25°C) or 2% (-40°C ≤ T_J ≤ +125°C) below its nominal value measured at 1V differential.
- 10. Ground pin current is the regulator quiescent current plus pass transistor base current. The total current drawn from the supply is the sum of the load current plus the ground pin current.



AP2210-3.6 Electrical Characteristics (V_{IN} = 4.6V, I_{OUT} = 100 μ A, C_{IN} = 1.0 μ F, C_{OUT} = 2.2 μ F, V_{EN} \geq 2.0V, T_J = +25°C, **Bold** typeface applies over -40°C \leq T_J \leq +125°C (Note 6), unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
		V : 6 (-1	_	1	0/
$\Delta V_{OUT}/V_{OUT}$	Output Voltage Accuracy	Variation from specified V _{OUT}	-2	_	2	%
ΔV _{OUT} /ΔΤ	Output Voltage Temperature	_		120	_	μV/°C
(ΔV _{ΟυΤ} /V _{ΟυΤ})/ΔΤ	Coefficient (Note 7)	_		48		ppm/°C
.,,	Line Deculation	V = 4 0V/t= 42 0V		1.5	4.5	
V _{RLINE}	Line Regulation	V _{IN} = 4.6V to 13.2V			12	mV
V	Load Degulation (Nate 0)	- 0.4mA to 200mA		1	6	
V_{RLOAD}	Load Regulation (Note 8)	I _{OUT} = 0.1mA to 300mA			30	mV
	Dropout Voltago (Note 9)	- 100vA		15	50	
		Ι _{ΟUT} = 100μΑ		_	70	
		I _{OUT} = 50mA		110	150	
V _{DROP} Dropout Voltage (Note 9)					230	-
		I _{OUT} = 100mA		140	250	
	100T - 100MA		_	300	mV	
		I _{OUT} = 150mA		165	275	
					350	
		- 200m A		250	400	
		I _{OUT} = 300mA		_	500	
	0, 1, 0	V _{EN} ≤ 0.4V (shutdown)		0.01	1	
I _{STD}	Standby Current	V _{EN} ≤ 0.18V (shutdown)	_	_	5	μA
		V > 0.0V 400vA	_	100	150	
		V _{EN} ≥ 2.0V, I _{OUT} = 100μA			180]
		V > 2.0V I = 50mA		350	600	μA
	One and Bir Output (Nata 40)	V _{EN} ≥ 2.0V, I _{OUT} = 50mA		_	800	
IGND	I _{GND} Ground Pin Current (Note 10)	V > 2.0V 450A		1.3	1.9	
	V _{EN} ≥ 2.0V, I _{OUT} = 150mA	_	_	2.5	mA	
	V > 2.0V = 200m4		4	10		
		V _{EN} ≥ 2.0V, I _{OUT} = 300mA		_	15	
PSRR	Ripple Rejection	f = 100Hz, I _{OUT} = 100μA		75		dB
I _{LIMIT}	Current Limit	V _{OUT} = 0V	_	450	900	mA



AP2210-3.6 Electrical Characteristics (Cont.) (V_{IN} = 4.6V, I_{OUT} = 100μA, C_{IN} = 1.0μF, C_{OUT} = 2.2μF, V_{EN} ≥ 2.0V, T_J = +25°C, **Bold** typeface applies over $-40^{\circ}\text{C} \le T_{\text{J}} \le +125^{\circ}\text{C}$ (Note 6), unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
e _{no}	Output Noise	I_{OUT} = 50mA, C_{OUT} = 2.2 μ F, 100pF from BYP to GND	_	260	_	nV/\sqrt{Hz}
.,					0.4	
V _{IL}	Enable Input Logic-low Voltage	Regulator shutdown	_	_	0.18	V
V _{IH}	Enable Input Logic-high Voltage	Regulator enabled	2.0	_	_	٧
	Enable Input Logic-low Current	V _{IL} ≤ 0.4V	_	0.01	1	
l _{IL}		V _{IL} ≤ 0.18V	_		2	μA
	Enable Input Logic-high Current	V _{IL} ≥ 2.0V	_	5	20	
lін		V _{IL} ≥ 2.0V	_	_	25	μΑ

- 6. Specifications in bold type are limited to -40°C ≤ T_J ≤ +125°C. Limits over temperature are guaranteed by design, but not tested in production.
- 7. Output voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.
- Output voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.
 Regulation is measured at constant junction temperature using low duty cycle pulse testing. Parts are tested for load regulation in the load range from 0.1mA to 300mA. Changes in output voltage due to heating effects are covered by the thermal regulation specification.
 Dropout voltage is defined as the input to output differential at which the output voltage drops 1% (T_J = +25°C) or 2% (-40°C ≤ T_J ≤ +125°C) below its nominal value measured at 1V differential.
- 10. Ground pin current is the regulator quiescent current plus pass transistor base current. The total current drawn from the supply is the sum of the load current plus the ground pin current.



AP2210-4.0 Electrical Characteristics (V_{IN} = 5.0V, I_{OUT} = 100 μ A, C_{IN} = 1.0 μ F, C_{OUT} = 2.2 μ F, V_{EN} \geq 2.0V, T_J = +25°C, **Bold** typeface applies over -40°C \leq T_J \leq +125°C (Note 6), unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
		V : 6 6 76 1V	-1	_	1	0/
ΔV _{OUT} /V _{OUT}	Output Voltage Accuracy	Variation from specified V _{OUT}	-2	_	2	%
ΔV _{OUT} /ΔΤ	Output Voltage Temperature	_	_	120	_	μV/°C
(ΔV _{ΟυΤ} /V _{ΟυΤ})/ΔΤ	Coefficient (Note 7)	_		48		ppm/°C
.,	Line Deculation	V = 5.0V/+= 42.0V		1.5	4.5	
V _{RLINE}	Line Regulation	V _{IN} = 5.0V to 13.2V	_		12	mV
V	Load Description (Nata 0)	- 0.1mA to 200mA		1	6	
V_{RLOAD}	Load Regulation (Note 8)	I _{OUT} = 0.1mA to 300mA			30	mV
		I - 400A		15	50	
		Ι _Ο Τ = 100μΑ	_	_	70	
		J - 50m A		110	150	
	Dropout Voltage (Note 9)	I _{OUT} = 50mA	_		230	
.,,		I _{OUT} = 100mA		140	250	mV
V_{DROP}				_	300	
		I _{OUT} = 150mA		165	275	
			_		350	
		I _{OUT} = 300mA		250	400	
			_	_	500	
		V _{EN} ≤ 0.4V (shutdown)	_	0.01	1	
I _{STD}	Standby Current	V _{EN} ≤ 0.18V (shutdown)		_	5	μA
		V > 0.0V 400vA	_	100	150	
		V _{EN} ≥ 2.0V, I _{OUT} = 100μA	_		180	
		V > 2.0V I = 50mA		350	600	μA
I _{GND}	Occupat Dia Occupat (Nata 40)	V _{EN} ≥ 2.0V, I _{OUT} = 50mA		_	800	
	Ground Pin Current (Note 10)	V > 2.0V 450A		1.3	1.9	
		V _{EN} ≥ 2.0V, I _{OUT} = 150mA	_	_	2.5	mA
		V > 2.0V = 200m2 A		4	10	
		V _{EN} ≥ 2.0V, I _{OUT} = 300mA	_	_	15	
PSRR	Ripple Rejection $f = 100$ Hz, $I_{OUT} = 100\mu$ A			75		dB
I _{LIMIT}	Current Limit	V _{OUT} = 0V	_	450	900	mA



AP2210-4.0 Electrical Characteristics (Cont.) (V_{IN} = 5.0V, I_{OUT} = 100μA, C_{IN} = 1.0μF, C_{OUT} = 2.2μF, V_{EN} ≥ 2.0V, T_J = +25°C, **Bold** typeface applies over $-40^{\circ}\text{C} \le T_{\text{J}} \le +125^{\circ}\text{C}$ (Note 6), unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
e _{no}	Output Noise	I_{OUT} = 50mA, C_{OUT} = 2.2 μ F, 100 μ F from BYP to GND	_	260	_	nV/\sqrt{Hz}
.,					0.4	.,
V_{IL}	Enable Input Logic-low Voltage	Regulator shutdown	_	_	0.18	V
V_{IH}	Enable Input Logic-high Voltage	Regulator enabled	2.0	_	_	٧
		V _{IL} ≤ 0.4V	_	0.01	1	
I _{IL}	Enable Input Logic-low Current	V _{IL} ≤ 0.18V	_	_	2	μA
		V _{IL} ≥ 2.0V	_	5	20	
IIH	Enable Input Logic-high Current	V _{IL} ≥ 2.0V		_	25	μΑ

- 6. Specifications in bold type are limited to -40°C ≤ T_J ≤ +125°C. Limits over temperature are guaranteed by design, but not tested in production.
- Specifications in bold type are limited to -40°C ≤ 1 3 ≤ +125°C. Limits over temperature are guaranteed by design, but not tested in production.
 Output voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.
 Regulation is measured at constant junction temperature using low duty cycle pulse testing. Parts are tested for load regulation in the load range from 0.1mA to 300mA. Changes in output voltage due to heating effects are covered by the thermal regulation specification.
 Dropout voltage is defined as the input to output differential at which the output voltage drops 1% (T_J = +25°C) or 2% (-40°C ≤ T_J ≤ +125°C) below its nominal value measured at 1V differential.
- 10. Ground pin current is the regulator quiescent current plus pass transistor base current. The total current drawn from the supply is the sum of the load current plus the ground pin current.



AP2210-5.0 Electrical Characteristics (V_{IN} = 6.0V, I_{OUT} = 100 μ A, C_{IN} = 1.0 μ F, C_{OUT} = 2.2 μ F, V_{EN} \geq 2.0V, T_J = +25°C, **Bold** typeface applies over -40°C \leq T_J \leq +125°C (Note 6), unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
		V : 6 6 76 1V	-1	_	1	0/
$\Delta V_{OUT}/V_{OUT}$	Output Voltage Accuracy	Variation from specified V _{OUT}	-2	_	2	%
ΔV _{OUT} /ΔΤ	Output Voltage Temperature	_		120	_	μV/°C
(ΔV _{ΟυΤ} /V _{ΟυΤ})/ΔΤ	Coefficient (Note 7)	_		48		ppm/°C
V	Line Degulation	V = 6.0V/to 12.2V/		1.5	4.5	- m\/
V _{RLINE}	Line Regulation	V _{IN} = 6.0V to 13.2V			12	mV
V	Lord Downlotter (Note 0)	- 0.4 m A to 200 m A		1	6	>/
V_{RLOAD}	Load Regulation (Note 8)	I _{OUT} = 0.1mA to 300mA			30	mV
		I - 100A		15	50	
		Ι _{ΟUT} = 100μΑ		_	70	
		- 50m A		110	150	
	Dropout Voltage (Note 9)	I _{OUT} = 50mA			230	mV
V		I _{OUT} = 100mA		140	250	
V_{DROP}				_	300	
		I _{OUT} = 150mA		165	275	
					350	
		I _{OUT} = 300mA		250	400	
				_	500	
	0, 1, 0	V _{EN} ≤ 0.4V (shutdown)		0.01	1	
I _{STD}	Standby Current	V _{EN} ≤ 0.18V (shutdown)	_	_	5	μA
		V > 0.0V 400vA	_	100	150	
		V _{EN} ≥ 2.0V, I _{OUT} = 100μA			180	
I _{GND}		V > 2.0V I = 50mA		350	600	μA
	One and Bir Output (Nata 40)	V _{EN} ≥ 2.0V, I _{OUT} = 50mA		_	800	
	Ground Pin Current (Note 10)	V > 2.0V 450=4		1.3	1.9	
		V _{EN} ≥ 2.0V, I _{OUT} = 150mA	_	_	2.5	mA
		V > 2.0V = 200mA		4	10	
		V _{EN} ≥ 2.0V, I _{OUT} = 300mA		_	15	
PSRR	Ripple Rejection f = 100Hz, I _{OUT} = 100μA			75		dB
I _{LIMIT}	Current Limit	V _{OUT} = 0V	_	450	900	mA



AP2210-5.0 Electrical Characteristics (Cont.) (V_{IN} = 6.0V, I_{OUT} = 100μA, C_{IN} = 1.0μF, C_{OUT} = 2.2μF, V_{EN} ≥ 2.0V, T_J = +25°C, **Bold** typeface applies over $-40^{\circ}\text{C} \le T_{\text{J}} \le +125^{\circ}\text{C}$ (Note 6), unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
e _{no}	Output Noise	I_{OUT} = 50mA, C_{OUT} = 2.2 μ F, 100pF from BYP to GND		260	_	nV/\sqrt{Hz}
.,			_		0.4	.,
V_{IL}	Enable Input Logic-low Voltage	Regulator shutdown	_	_	0.18	V
V _{IH}	Enable Input Logic-high Voltage Regulator enabled		2.0			V
		V _{IL} ≤ 0.4V	_	0.01	1	
I _{IL}	Enable Input Logic-low Current	V _{IL} ≤ 0.18V	_		2	μΑ
I _{IH}	Enable Input Logic-high Current	V _{IL} ≥ 2.0V	_	5	20	
		V _{IL} ≥ 2.0V	_	_	25	μΑ

- 6. Specifications in bold type are limited to -40°C ≤ T_J ≤ +125°C. Limits over temperature are guaranteed by design, but not tested in production.
- Specifications in bold type are limited to -40°C ≤ 1 3 ≤ +125°C. Limits over temperature are guaranteed by design, but not tested in production.
 Output voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.
 Regulation is measured at constant junction temperature using low duty cycle pulse testing. Parts are tested for load regulation in the load range from 0.1mA to 300mA. Changes in output voltage due to heating effects are covered by the thermal regulation specification.
 Dropout voltage is defined as the input to output differential at which the output voltage drops 1% (T_J = +25°C) or 2% (-40°C ≤ T_J ≤ +125°C) below its nominal value measured at 1V differential.
- 10. Ground pin current is the regulator quiescent current plus pass transistor base current. The total current drawn from the supply is the sum of the load current plus the ground pin current.



AP2210-ADJ Electrical Characteristics ($V_{IN} = V_{OUT} + 1V$, $I_{OUT} = 100\mu A$, $C_{IN} = 1.0\mu F$, $C_{OUT} = 2.2\mu F$, $V_{EN} \ge 2.0V$, $T_J = +25^{\circ}C$, **Bold** typeface applies over $-40^{\circ}\text{C} \le T_{\text{J}} \le +125^{\circ}\text{C}$ (Note 6), unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
	Outrot Vallage Assume	Variation from a difficulty	-1	_	1	0/	
$\Delta V_{OUT}/V_{OUT}$	Output Voltage Accuracy	Variation from specified V _{OUT}	-2	_	2	%	
$\Delta V_{OUT}/\Delta T$	Output Voltage Temperature	_	_	120		μV/°C	
$(\Delta V_{OUT}/V_{OUT})/\Delta T$	Coefficient (Note 7)			48		ppm/°C	
V	Line Deculation	$V_{IN} = V_{OUT} + 1V$ to 13.2V		1.5	4.5	>/	
V_{RLINE}	Line Regulation	VIN = VOUT+1V (0 13.2V	_	_	12	mV	
W	Load Decidation (Nata 9)	I _{OUT} = 0.1mA to 300mA		1	6	> /	
V _{RLOAD}	Load Regulation (Note 8)	10UT = 0. IIIIA (0 300IIIA	_	_	30	mV	
	Chandley Cymant	V _{EN} ≤ 0.4V (shutdown)		0.01	1		
I _{STD}	Standby Current	V _{EN} ≤ 0.18V (shutdown)	_	_	5	μΑ	
	I _{GND} Ground Pin Current (Note 10)	V > 2.0V I = 400··A		100	150	μΑ	
		V _{EN} ≥ 2.0V, I _{OUT} = 100μA			180		
		V _{EN} ≥ 2.0V, I _{OUT} = 50mA		350	600		
				_	800		
IGND		V _{EN} ≥ 2.0V, I _{OUT} = 150mA	_	1.3	1.9		
			_	_	2.5		
		V > 0.0V 0.00 A	_	4	10	mA	
		$V_{EN} \ge 2.0V$, $I_{OUT} = 300mA$	_	_	15		
PSRR	Ripple Rejection	f = 100Hz, I _{OUT} = 100μA	_	75	_	dB	
I _{LIMIT}	Current Limit	V _{OUT} = 0V	_	450	900	mA	
e _{no}	Output Noise	I_{OUT} = 50mA, C_{OUT} = 2.2 μ F, 100pF from BYP to GND	_	260		nV/\sqrt{Hz}	
	Fachla land Land Land Vallana	De mulatan alkutdanını			0.4	.,,	
V_{IL}	Enable Input Logic-low Voltage	Regulator shutdown	_	_	0.18	V	
V _{IH}	Enable Input Logic-high Voltage	Regulator enabled	2.0	_		V	
	Fachla land I aria lan 0	V _{IL} ≤ 0.4V	_	0.01	1		
I _{IL}	Enable Input Logic-low Current	V _{IL} ≤ 0.18V	_	_	2	μA	
		V _{IL} ≥ 2.0V	_	5	20		
I _{IH}	Enable Input Logic-high Current	V _{IL} ≥ 2.0V	_	_	25	μΑ	

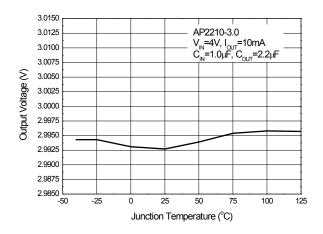
Specifications in bold type are limited to -40°C ≤ T_J ≤ +125°C. Limits over temperature are guaranteed by design, but not tested in production.
 Output voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.
 Regulation is measured at constant junction temperature using low duty cycle pulse testing. Parts are tested for load regulation in the load range from 0.1mA to 300mA. Changes in output voltage due to heating effects are covered by the thermal regulation specification.
 Dropout voltage is defined as the input to output differential at which the output voltage drops 1% (T_J = +25°C) or 2% (-40°C ≤ T_J ≤ +125°C) below its nominal value measured at 1V differential.

^{10.} Ground pin current is the regulator quiescent current plus pass transistor base current. The total current drawn from the supply is the sum of the load current plus the ground pin current.

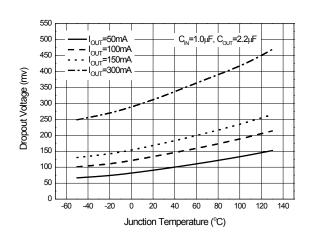


Performance Characteristics

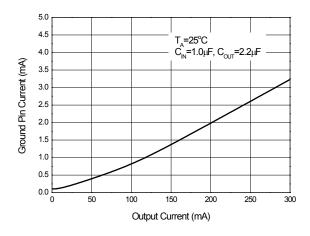
Output Voltage vs. Junction Temperature



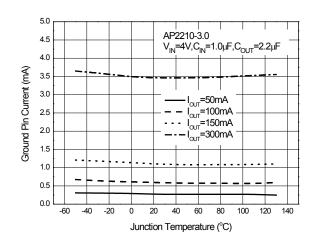
Dropout Voltage vs. Junction Temperature



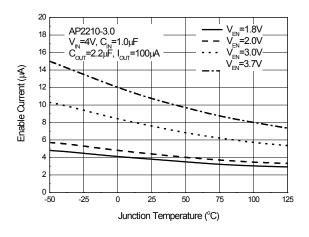
Ground Pin Current vs. Output Current



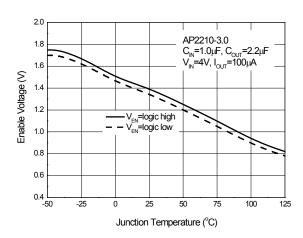
Ground Pin Current vs. Junction Temperature



Enable Current vs. Junction Temperature



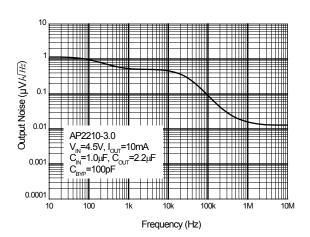
Enable Voltage vs. Junction Temperature



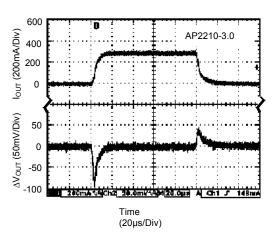


Performance Characteristics (Cont.)

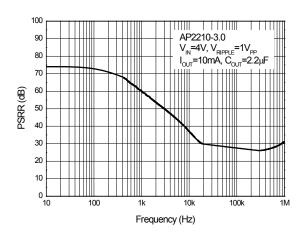
Output Noise vs. Frequency

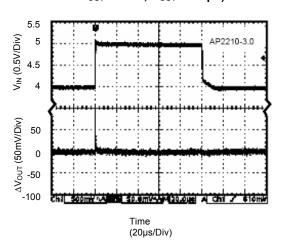


 $\label{eq:lower} Load\ Transient$ (Conditions: V_IN = 4V, V_EN = 2V, I_{OUT} = 10mA to 300mA, C_IN = 1.0 μ F, C_OUT = 2.2 μ F)

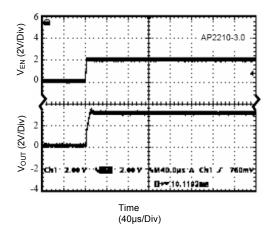


PSRR vs. Frequency

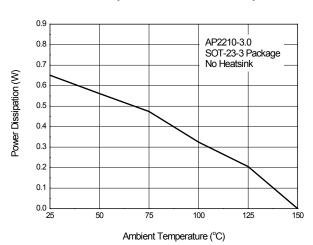




 $\begin{aligned} &V_{EN} \text{ vs. } V_{OUT}\\ \text{(Conditions: } V_{EN} = 0 \text{ to 2V, } V_{IN} = 4V,\\ I_{OUT} = 30\text{mA, } C_{IN} = 1.0 \mu\text{F, } C_{OUT} = 2.2 \mu\text{F)} \end{aligned}$



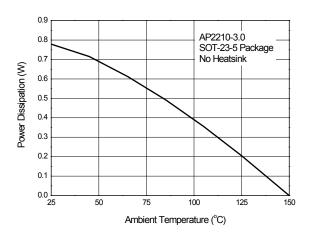
Power Dissipation vs. Ambient Temperature



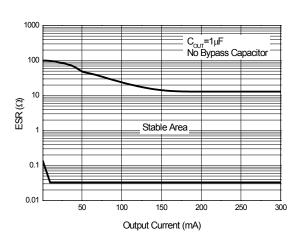


Performance Characteristics (Cont.)

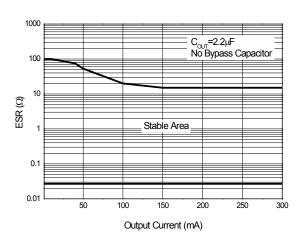
Power Dissipation vs. Ambient Temperature



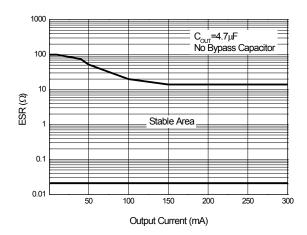
ESR vs. Output Current



ESR vs. Output Current



ESR vs. Output Current





Application Information

Input Capacitor

A 1µF minimum capacitor is recommended to be placed between V_{IN} and GND.

Output Capacitor

An output capacitor is required to prevent oscillation. A $1.0\mu F$ minimum is recommended when C_{BYP} is unused. A $2.2\mu F$ minimum is recommended when C_{BYP} is 100pF. The output capacitor may be increased to improve transient response.

Noise Bypass Capacitor

A bypass capacitor is connected to the internal voltage reference. A small capacitor connected from BYP to GND makes this reference quiet, resulting in a significant reduction in output noise, but the ESR stable area will be narrowed. In order to keep the output stability, it is recommended to use the bypass capacitor no more than 100pF.

The start-up speed of the AP2210 is inversely proportional to the value of the reference bypass capacitor. In some cases, if output noise is not a major concern and rapid turn-on is necessary, omit C_{BYP} and leave BYP open.

Power Dissipation

Thermal shutdown may take place if the maximum power dissipation is exceeded in application. Under all possible operating conditions, the junction temperature must be within the range specified under absolute maximum ratings to avoid thermal shutdown.

To determine if the power dissipated in the regulator reaches the maximum power dissipation (see Figure Power Dissipation vs. Ambient Temperature and Figure ESR vs. Output Current in Page 22), use:

$$T_J = P_D^*\theta_{JA} + T_A$$

 $P_D = (V_{IN}-V_{OUT})*I_{OUT}+V_{IN}*I_{GND}$

Where: $T_J \le T_{J(max)}$, $T_{J(max)}$ is absolute maximum ratings for the junction temperature; $V_{IN}^*I_{GND}$ can be ignored due to its small value.

 $T_{J(max)}$ is +150°C, θ_{JA} is 200°C/W, no heatsink is required since the package alone will dissipate enough heat to satisfy these requirements, unless the calculated value for power dissipation exceeds the limit.

Example (3.0V version):

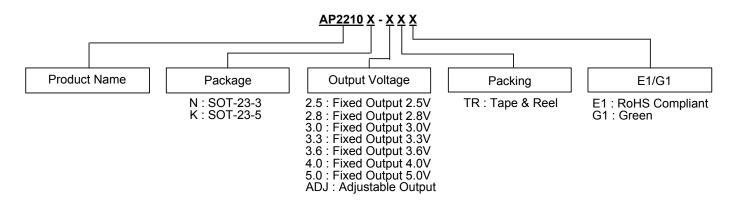
 $I_{OUT} = 300 \text{mA}, T_A = +50^{\circ}\text{C}, V_{IN(Max)} \text{ is:}$

(150°C-50°C)/(0.3A*200°C/W)+3.0V=4.67V

Therefore, for good performance, please make sure that the input voltage is less than 4.67V without heatsink when $T_A = +50$ °C.



Ordering Information



	Temperature		Part N	Part Number		ing ID		
	Package	Range	RoHS Compliant	Green	RoHS Compliant	Green	Packing	
			AP2210N-2.8TRE1 (Note 11)	AP2210N-2.8TRG1	EH3	GH3	3000/Tape & Reel	
			AP2210N-3.0TRE1 (Note 11)	AP2210N-3.0TRG1	EH4	GH4	3000/Tape & Reel	
Lead-Free			AP2210N-3.3TRE1 (Note 11)	AP2210N-3.3TRG1	EH5	GH5	3000/Tape & Reel	
Pb	SOT-23-3	-40°C to +85°C	_	AP2210N-3.6TRG1	_	GB7	3000/Tape & Reel	
Lead-free Green			_	AP2210N-4.0TRG1	_	GC7	3000/Tape & Reel	
			_	AP2210N-5.0TRG1	_	GH9	3000/Tape & Reel	
		23-5 -40°C to +85°C	AP2210K-2.5TRE1 (Note 11)	_	E5C	_	3000/Tape & Reel	
			AP2210K-2.8TRE1 (Note 11)	AP2210K-2.8TRG1	E5F	G5F	3000/Tape & Reel	
			AP2210K-3.0TRE1 (Note 11)	AP2210K-3.0TRG1	E5H	G5H	3000/Tape & Reel	
Lead-Free			AP2210K-3.3TRE1 (Note 11)	AP2210K-3.3TRG1	E5K	G5K	3000/Tape & Reel	
Pb	SOT-23-5		_	AP2210K-3.6TRG1	_	G5I	3000/Tape & Reel	
Lead-free Green			_	AP2210K-4.0TRG1	_	G5J	3000/Tape & Reel	
			_	AP2210K-5.0TRG1		G5L	3000/Tape & Reel	
			_	AP2210K-ADJTRG1	_	G5M	3000/Tape & Reel	

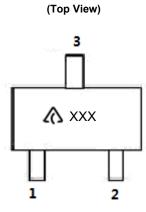
Notes:

11. Not recommended for new design.



Marking Information

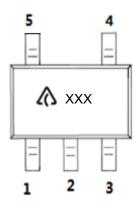
(1) SOT-23-3



★ : Logo
XXX: Marking ID
(See Ordering Information)

(2) SOT-23-5



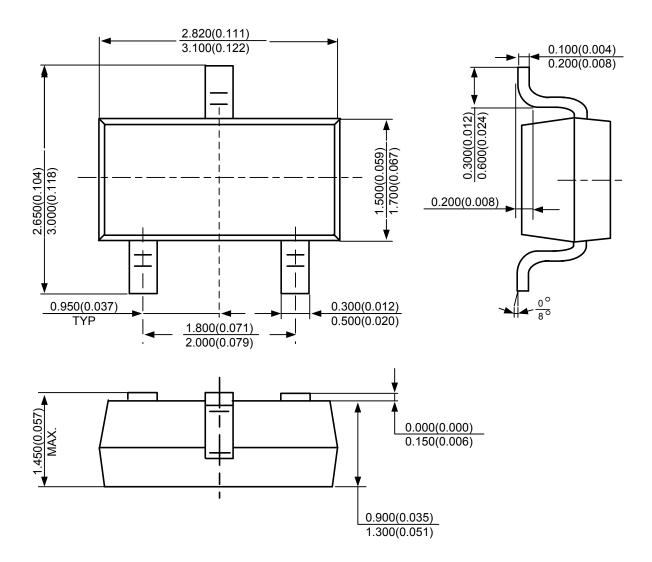


♠ : Logo
XXX: Marking ID
(See Ordering Information)



Package Outline Dimensions (All dimensions in mm(inch).)

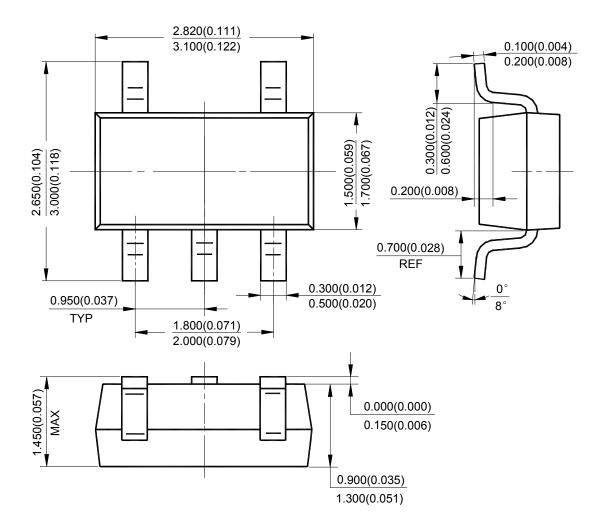
(1) Package Type: SOT-23-3





Package Outline Dimensions (Cont. All dimensions in mm(inch).)

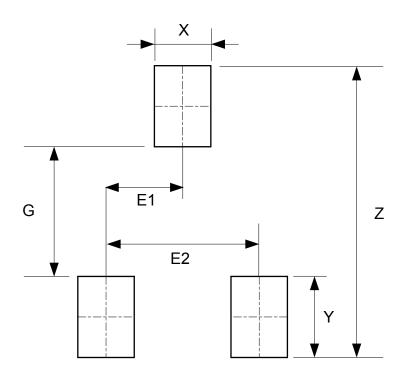
(2) Package Type: SOT-23-5





Suggested Pad Layout

(1) Package Type: SOT-23-3

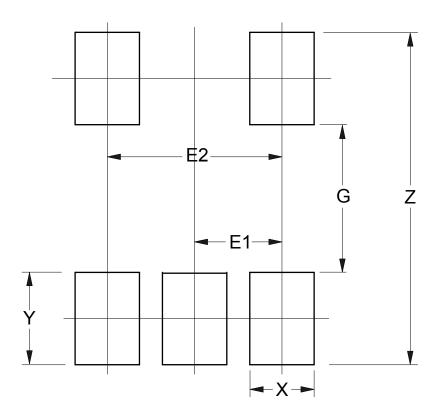


Dimensions	Z	G	X	Y	E1	E2
	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)
Value	3.600/0.142	1.600/0.063	0.700/0.028	1.000/0.039	0.950/0.037	1.900/0.075



Suggested Pad Layout (Cont.)

(2) Package Type: SOT-23-5



Dimonoione	Z	G	X	Y	E1	E2
Dimensions	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)
Value	3.600/0.142	1.600/0.063	0.700/0.028	1.000/0.039	0.950/0.037	1.900/0.075



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